

SHDT173012

3A HERMETIC THIN
SCHOTTKY DIODE

TECHNICAL DATA
DATA SHEET 5548 Preliminary

AVAILABLE	AS
SX	
SS	

HERMETIC THIN DIODE Schottky Rectifier

DESCRIPTION:

This low profile, hermetically sealed, schottky rectifier diode is manufactured on a MIL-PRF-19500 JANS qualified line and is designed for space solar array applications. The silver plated flat leads are designed for ease in welding to solar array PCBs.

FEATURES / BENEFITS:

- ✓ Silver plated flat leads
- ✓ Hermetic, cavity ceramic package
- ✓ JANS Equivalent screening and QCI available

MAXIMUM RATINGS:

- ✓ Operating & Storage Temperature: -55°C to +150°C
- ✓ Extended Temperature Range: -195°C to 150°C (Temperature Shock)
- ✓ Thermal Resistance: 22°C/W (junction to lead)

ELECTRICAL CHARACTERISTICS

MAX. RATINGS / ELECTRICAL CHARACTERISTICS All ratings are at $T_A = 25^{\circ}$ C unless otherwise specified.

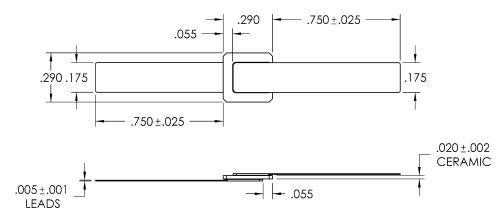
RATING	CONDITIONS	MIN	TYP	MAX	UNIT
Peak Inverse Voltage (PIV)	-	-	-	20	V dc
Average DC Output Current (I _o)	$T_A = +55^{\circ}C$	-	-	3	Α
Peak Single Cycle Surge Current (I _{fsm})	$t_{\rm p}$ = 8.3 ms Single Half Cycle Sine Wave, Superimposed on Rated Load	-	-	40	A (pk.)
Operating and Storage Temp. (T _{op} & T _{stg})	-	-55	-	+150	ç
Maximum Forward Voltage (V _f)	If = 3A (300 μ sec pulse, duty cycle < 2%) $T_J = 25$ °C $T_J = 125$ °C	-	0.56 0.51	0.59 0.54	Volts
Maximum Instantaneous Reverse Current At Rated	T _A = 25°C	-	0.1	0.3	mA
(PIV)	T _A = 125°C		8	14	
Max. Junction Capacitance (C_T)	$@V_R = 5V, T_C = 25 \text{ °C}$ $f_{SIG} = 1MHz, V_{SIG} = 50mV$	-	-	160	pF
Thermal Resistance (θ _{JL})	Junction to Lead d = 0.375"			22	°C/W

<u>SENSITRON</u> SEMICONDUCTOR

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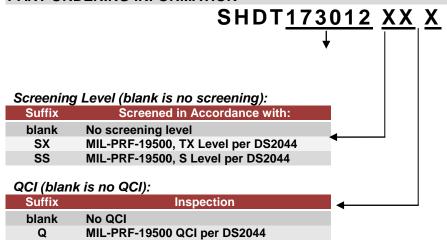
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PACKAGE DIMENSIONS (inches/mm)



TFP-1, THIN PACKAGE

PART ORDERING INFORMATION



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